imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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Central Semiconductor Corp.

www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMKT3904 (two single NPN) and CMKT3906 (two single PNP) are silicon transistors in a space saving SOT-363 package, designed for small signal general purpose amplifier and switching applications.

MARKING CODES: CMKT3904: K04 CMKT3906: K06

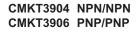
FEATURES:

• Two NPN (3904) or Two PNP (3906) Transistors in a single package

MAXIMUM RATINGS: (T _A =25°C)	SYMBOL	NPN	PNP	UNITS
Collector-Base Voltage	V _{CBO}	60	40	V
Collector-Emitter Voltage	VCEO	40	40	V
Emitter-Base Voltage	VEBO	6.0	5.0	V
Continuous Collector Current	I _C	20	00	mA
Power Dissipation	PD	350		mW
Operating and Storage Junction Temperature	т _Ј , Т _{stg}	-65 to	+150	°C
Thermal Resistance	ΘJA	35	57	°C/W

ELECTRICAL CHARACTERISTICS PER TRANSISTOR: (TA=25°C unless otherwise noted)

		<u>NPN</u>			1P	
SYMBOL	TEST CONDITIONS	MIN	MAX	MIN	MAX	UNITS
ICEV	V _{CE} =30V, V _{EB} =3.0V	-	50	-	50	nA
I _{BL}	V _{CE} =30V, V _{EB} =3.0V	-	50	-	-	nA
BVCBO	Ι _C =10μΑ	60	-	40	-	V
BVCEO	I _C =1.0mA	40	-	40	-	V
BVEBO	Ι _Ε =10μΑ	6.0	-	5.0	-	V
V _{CE(SAT)}	I _C =10mA, I _B =1.0mA	-	0.20	-	0.25	V
V _{CE(SAT)}	I _C =50mA, I _B =5.0mA	-	0.30	-	0.40	V
V _{BE(SAT)}	I _C =10mA, I _B =1.0mA	0.65	0.85	0.65	0.85	V
V _{BE(SAT)}	I _C =50mA, I _B =5.0mA	-	0.95	-	0.95	V
h _{FE}	V _{CE} =1.0V, I _C =0.1mA	40	-	60	-	
h _{FE}	V _{CE} =1.0V, I _C =1.0mA	70	-	80	-	
h _{FE}	V _{CE} =1.0V, I _C =10mA	100	300	100	300	
h _{FE}	V _{CE} =1.0V, I _C =50mA	60	-	60	-	
h _{FE}	V _{CE} =1.0V, I _C =100mA	30	-	30	-	
fT	V _{CE} =20V, I _C =10mA, f=100MHz	300	-	250	-	MHz
Cob	V _{CB} =5.0V, I _E =0, f=1.0MHz	-	4.0	-	4.5	pF
C _{ib}	V _{BE} =0.5V, I _C =0, f=1.0MHz	-	8.0	-	10	рF
					R6 (23	3-September 2013)

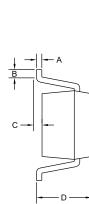




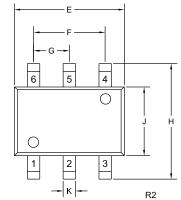
SURFACE MOUNT SILICON DUAL SMALL SIGNAL SWITCHING TRANSISTORS

ELECTRICAL CHARACTERISTICS PER TRANSISTOR - Continued: $(T_A=25^{\circ}C)$

			<u>NPN</u>		PNP	
SYMBOL	TEST CONDITIONS	MIN	MAX	MIN	MAX	UNITS
h _{ie}	V _{CE} =10V, I _C =1.0mA, f=1.0kHz	1.0	10	2.0	12	kΩ
h _{re}	V _{CE} =10V, I _C =1.0mA, f=1.0kHz	0.5	8.0	0.1	10	x10 ⁻⁴
h _{fe}	V _{CE} =10V, I _C =1.0mA, f=1.0kHz	100	400	100	400	
h _{oe}	V _{CE} =10V, I _C =1.0mA, f=1.0kHz	1.0	40	3.0	60	μS
NF	$V_{CE}\text{=}5.0\text{V},\text{I}_{C}\text{=}100\mu\text{A},\text{R}_{S}\text{=}1.0\text{k}\Omega,\text{f}\text{=}10\text{Hz}$ to 15.7kHz	-	5.0	-	4.0	dB
^t d	V_{CC} =3.0V, V_{BE} =0.5V, I _C =10mA, I _{B1} =1.0mA	-	35	-	35	ns
t _r	V_{CC} =3.0V, V_{BE} =0.5V, I _C =10mA, I _{B1} =1.0mA	-	35	-	35	ns
t _s	V _{CC} =3.0V, I _C =10mA, I _{B1} =I _{B2} =1.0mA	-	200	-	225	ns
t _f	V _{CC} =3.0V, I _C =10mA, I _{B1} =I _{B2} =1.0mA	-	50	-	75	ns







DIMENSIONS					
	INCHES		MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MAX	
А	0.004	0.010	0.10	0.25	
В	0.005	-	0.12	-	
С	0.000	0.004	0.00	0.10	
D	0.031	0.043	0.80	1.10	
E	0.071	0.087	1.80	2.20	
F	0.051		1.30		
G	0.026		0.65		
Н	0.075	0.091	1.90	2.30	
J	0.043	0.055	1.10	1.40	
K	0.006	0.012	0.15	0.30	

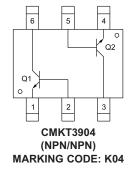
LEAD CODES: 1) Emitter Q1

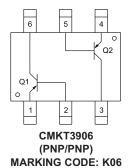
6) Collector Q1

2) Base Q1
3) Collector Q2
4) Emitter Q2
5) Base Q2

SOT-363 (REV: R2)

PIN CONFIGURATIONS





R6 (23-September 2013)

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OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- · Environmental regulation compliance
- Customer specific screening
- · Up-screening capabilities

· Custom product packing

Custom bar coding for shipments

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

REQUESTING PRODUCT PLATING

- If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when 1. ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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